

»Features

- 25Watts peak pulse power ($t_p = 8/20\mu s$)
- Unidirectional configurations
- Solid-state silicon-avalanche technology
- Low clamping voltage
- Low leakage current
- Low capacitance ($C_j = 0.3pF$ typ. I/O to I/O)
- IEC 61000-4-2 $\pm 10kV$ contact $\pm 12kV$ air
- Low clamping voltage: $V_{CL} = 5.3V$ typ @ $I_{PP} = 16A$ (TLP)
- IEC 61000-4-5 (Lightning) 5A ($8/20\mu s$)



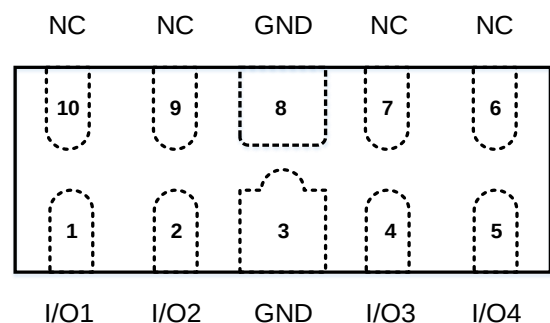
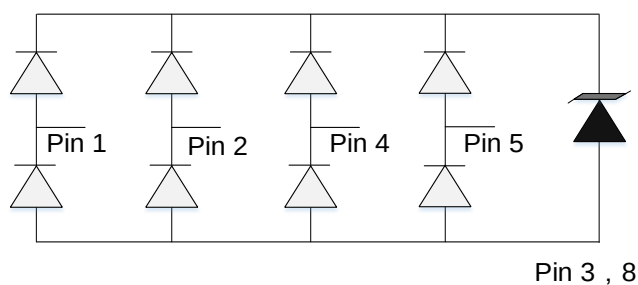
»Applications

- USB 3.0 and USB3.1
- HDMI1.3, HDMI1.4 and HDMI2.0
- Very sensitive interface lines
- Notebooks, Desktops, and Servers
- Industrial equipment

»Mechanical Data

- Tiny DFN10L(2.5mmx1.0mm) package
- Molding compound flammability rating: UL 94V-0
- Packaging: Tape and Reel
- RoHS/WEEE Compliant

»Schematic & PIN Configuration



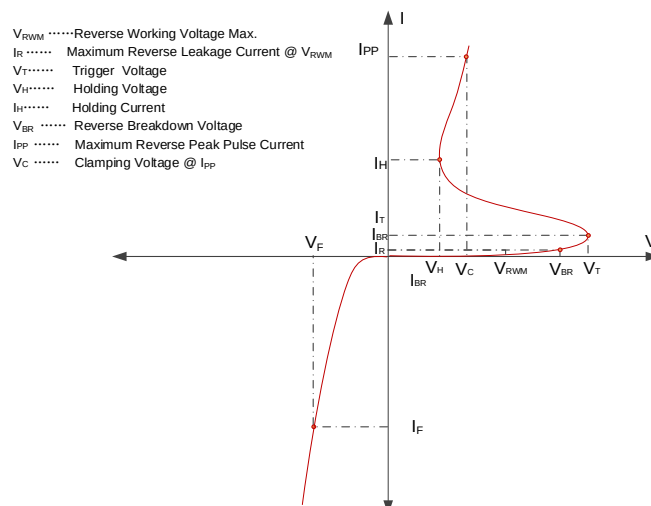
»Absolute Maximum Rating

Rating	Symbol	Value	Units
Peak Pulse Power ($t_p=8/20\mu s$)	P_{PP}	25	Watts
Peak Pulse Current ($t_p=8/20\mu s$) (note1)	I_{PP}	5	A
ESD per IEC 61000-4-2 (Air) ESD per IEC 61000-4-2 (Contact)	V_{ESD}	12 10	kV
Lead Soldering Temperature	T_L	260(10seconds)	°C
Junction Temperature	T_J	-55 to + 125	°C
Storage Temperature	T_{stg}	-55 to + 125	°C

»Electrical Characteristics

Parameter	Symbol	Conditions	Min	Typical	Max	Units
Reverse Stand-Off Voltage	V_{RWM}				3.3	V
Holding Voltage	V_H		2.0		3.3	V
Reverse Leakage Current	I_R	$V_{RWM}=3.3V, T=25^\circ C$			500	nA
Trigger Voltage	V_T			8.0		
Clamping Voltage	V_{CL}	$I_{PP}=16A, t_p=100ns$		5.3	6	V
Clamping Voltage	V_C	$I_{PP}=5A, t_p=8/20\mu s$			5	V
dynamic resistance	R_{dyn}	$T_{amb}=25^\circ C, I_R=10A$		0.3	0.4	Ω
Junction Capacitance	C_j	$V_R = 0V, f = 1MHz$ I/O to I/O		0.3		pF
		$V_R = 0V, f = 1MHz$ I/O to GND		0.55		pF

»Electrical Parameters (I/O to GND, $T_A = 25^\circ C$ unless otherwise noted)

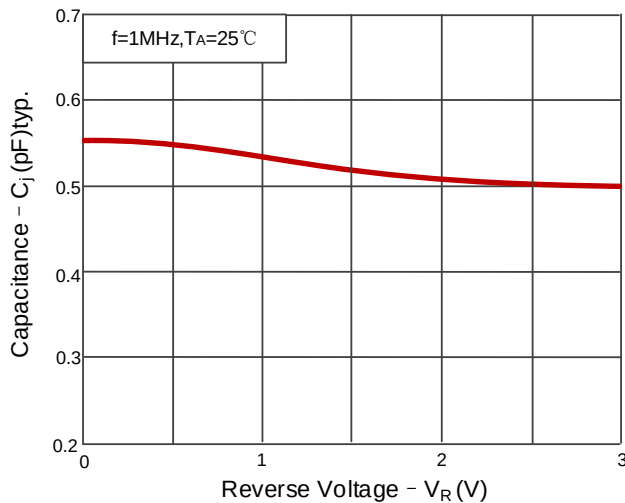


Note: 8/20 μs pulse waveform.

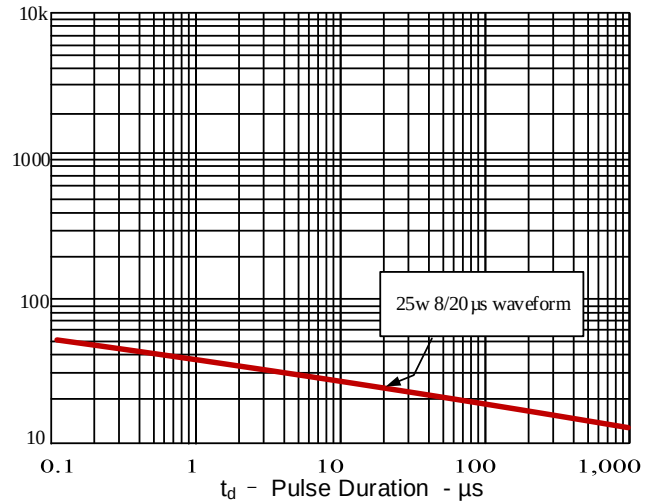
Ver.1.0

»Typical Characteristic Curves

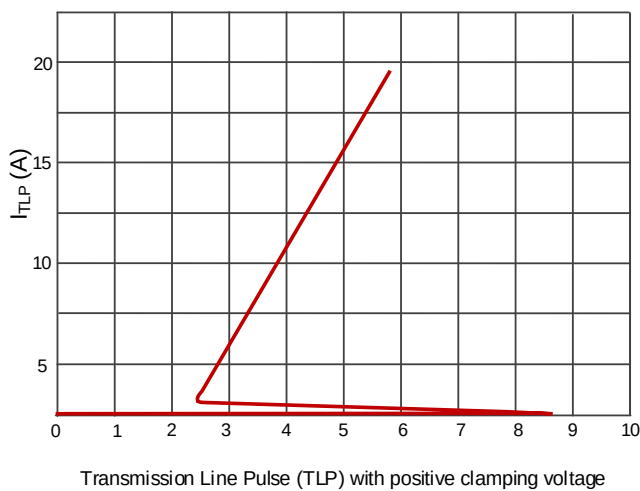
Capacitance vs. Reverse Voltage



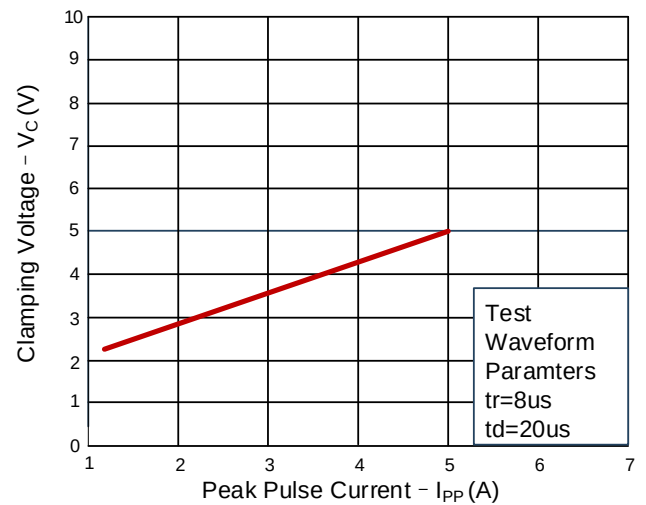
Peak Pluse Power vs. Pluse Time



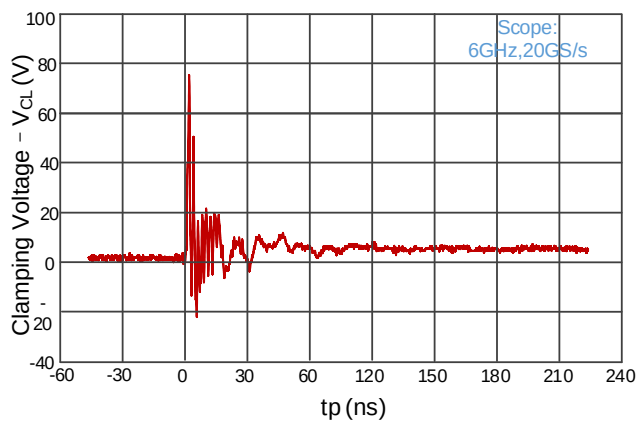
Positive Clamping voltage (TLP)



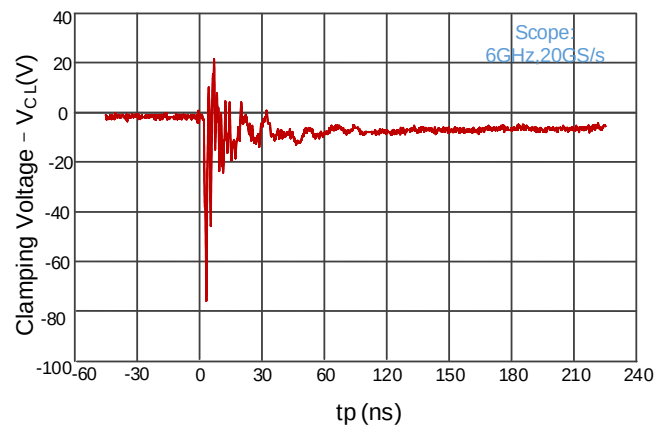
Reverse Clamping Voltage vs. Peak Pulse Current

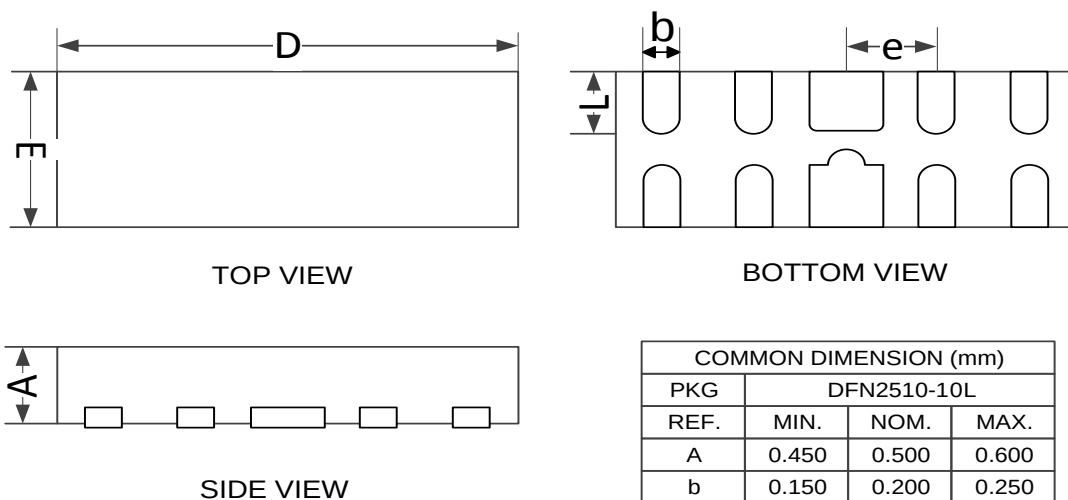
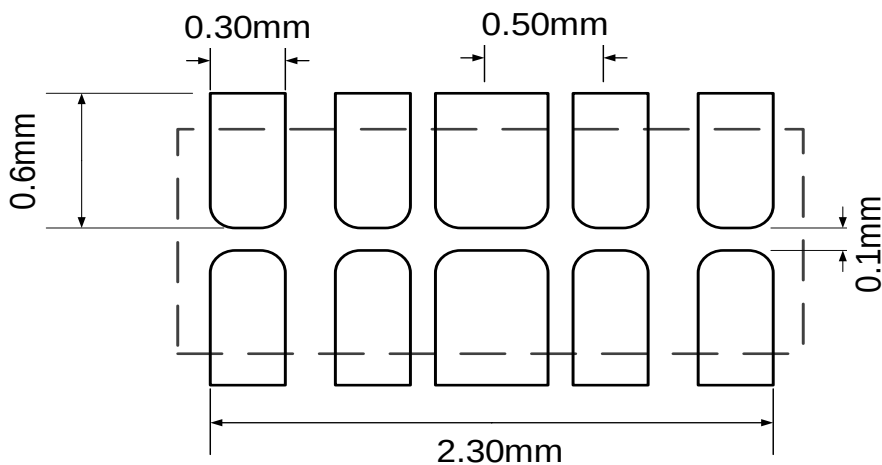


IEC61000-4-2 : 8 kV positive pulse(I/O to GND)



IEC61000-4-2 : 8 kV positive pulse(GND to I/O)



»Package information – DFN10L(2.5mmx1.0mm)

»Recommend PCB Layout


Notes: This PCB Layout Is For Reference Purposes Only.